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Daug

ST5150SAX SCHOTTKY RECTIFIER

Features

- Ultralow Forward Voltage Drop
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	150	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _A =105°C, rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T_c =25°C	80	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 2A, Pulse, T _J = 25 °C	0.68	0.70	V
		@ 5A, Pulse, T _J = 25 °C	1.09	1.20	v
	V _{F2}	@ 2A, Pulse, T _J = 125 °C	0.55	0.60	V
		@ 5A, Pulse, T _J = 125 °C	0.69	0.80	v
Reverse Current*	I _{R1}	$@V_R$ = Rated V _R , Pulse, T _J = 25 °C	0.001	0.1	mA
	I _{R2}	$@V_R = Rated V_R, Pulse, T_J = 125 °C$	3	15	mA
		@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	200	-	pF

* Pulse width < 300 µs, duty cycle < 2%

Circuit Diagram







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ST5150SAX





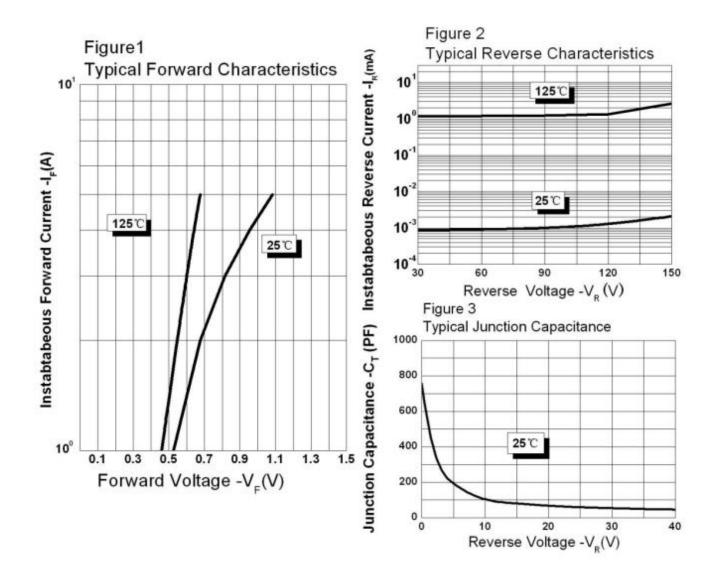
ST5150SAX

Technical Data Data Sheet N1617, Rev.A RoHS 🗭

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	4.5	°C/W
Approximate Weight	wt	-	1.00	g

Ratings and Characteristics Curves



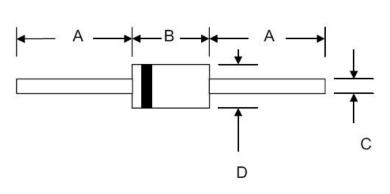


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Mechanical Dimensions DO-201AE



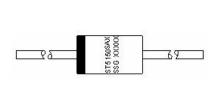
SYMDOL	Millim	neters	Inches	
SYMBOL	Min.	Max.	Min.	Max.
А	25.4	-	1.000	-
В	7.20	9.50	0.283	0.374
С	0.94	1.07	0.037	0.042
D	4.80	5.30	0.189	0.209

Ordering Information

Device	Package	Shipping
ST5150SAX	DO-201AE	2000noo / tano
5151505AX	(Pb-Free)	3000pcs / tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

- = Device Type
- = Forward Current (5A)
- = Reverse Voltage (150V) SAX = Package type
 - = SSG
- SSG = Year

ST

YΥ

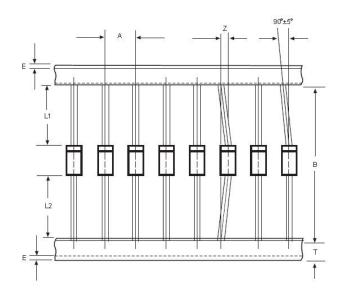
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5 150

- WW = Week
 - = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DO-201AE



SYMBOL	Millimeters		
	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	

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